

# 7MBR75VP060-50

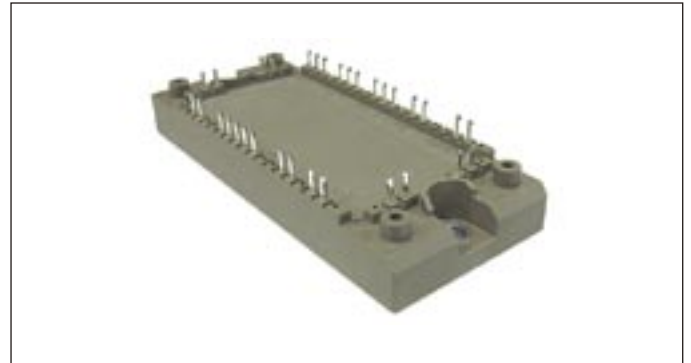
## IGBT MODULE (V series) 600V / 50A / PIM

### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant product

### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units	
Inverter	Collector-Emitter voltage	$V_{CES}$	600	V	
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V	
	Collector current	$I_c$	Continuous $T_c=80^\circ\text{C}$	75	A
		$I_{cp}$	1ms $T_c=80^\circ\text{C}$	150	
		$-I_c$		75	
$-I_c$ pulse		1ms	150		
Collector power dissipation	$P_c$	1 device	300	W	
Brake	Collector-Emitter voltage	$V_{CES}$	600	V	
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V	
	Collector current	$I_c$	Continuous $T_c=80^\circ\text{C}$	50	A
		$I_{cp}$	1ms $T_c=80^\circ\text{C}$	100	
	Collector power dissipation	$P_c$	1 device	215	W
Repetitive peak reverse voltage (Diode)	$V_{RRM}$		600	V	
Converter	Repetitive peak reverse voltage	$V_{RRM}$	800	V	
	Average output current	$I_o$	50Hz/60Hz, sine wave	75	A
	Surge current (Non-Repetitive)	$I_{FSM}$	10ms, $T_j=150^\circ\text{C}$	500	A
	$I^2t$ (Non-Repetitive)	$I^2t$	half sine wave	1250	$\text{A}^2\text{s}$
Junction temperature	$T_j$	Inverter, Brake	175	$^\circ\text{C}$	
		Converter	150		
Operating junction temperature (under switching conditions)	$T_{jop}$	Inverter, Brake	150		
		Converter	150		
Case temperature	$T_c$		125		
Storage temperature	$T_{stg}$		-40 to +125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	$V_{iso}$	AC : 1min.	2500	VAC
Screw torque	Mounting (*3)	-	M5	3.5	N m

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

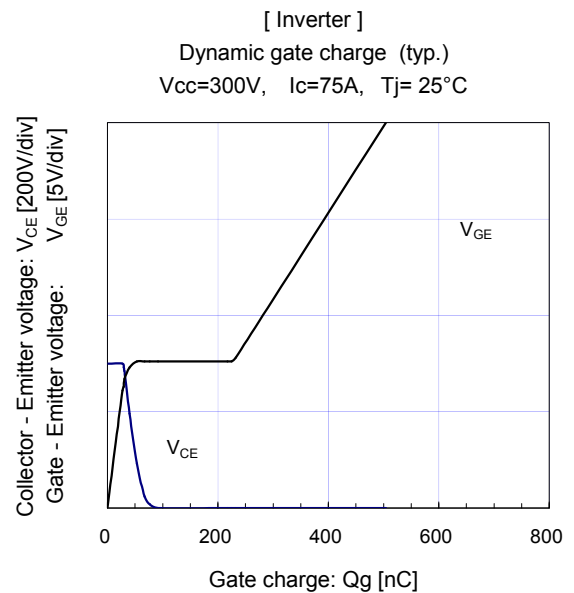
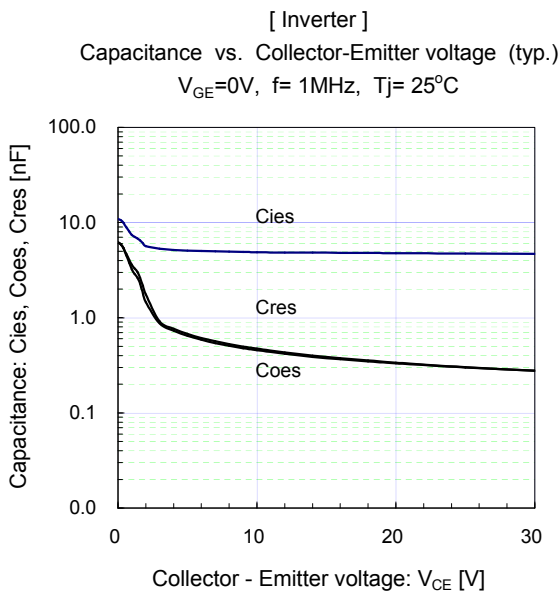
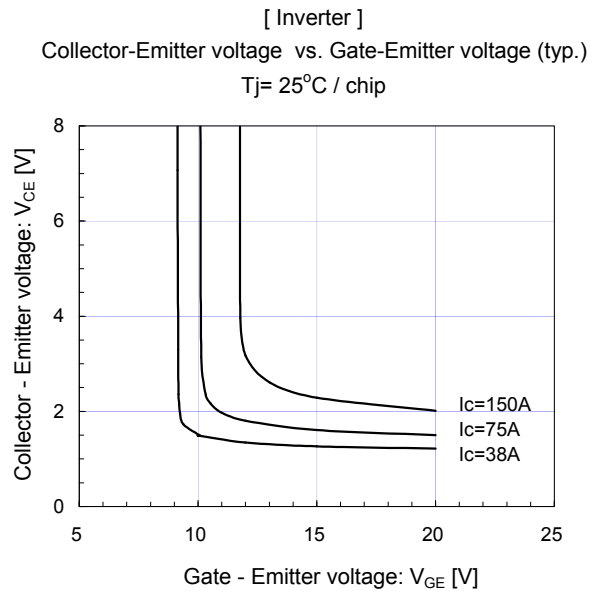
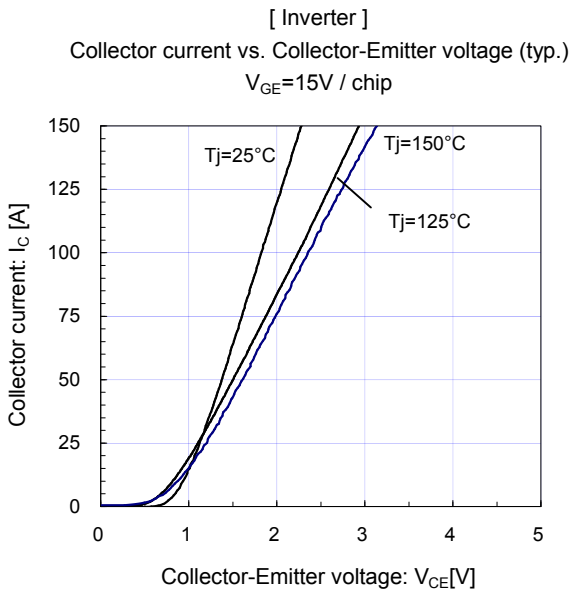
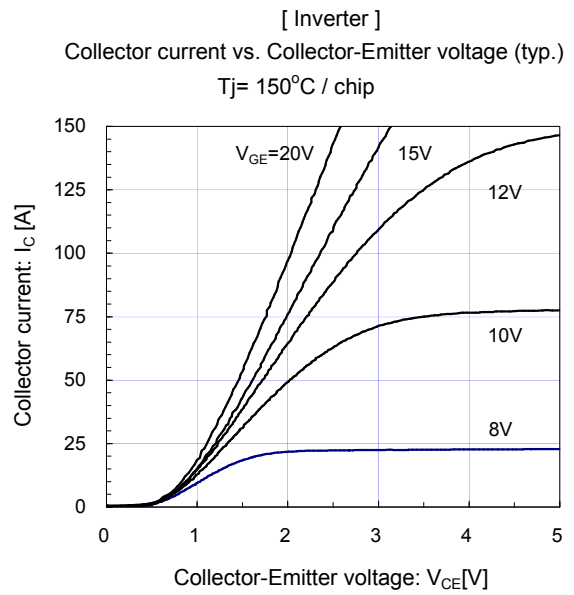
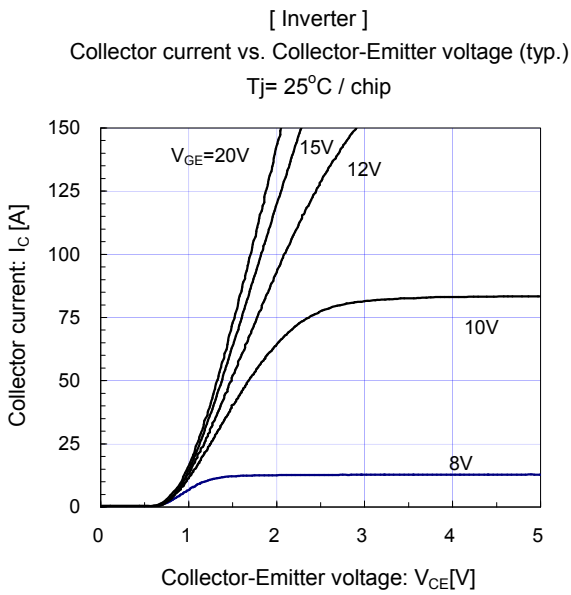
Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Zero gate voltage collector current	$I_{CES}$	$V_{GE} = 0V, V_{CE} = 600V$	-	-	1.0	mA	
	Gate-Emitter leakage current	$I_{GES}$	$V_{GE} = 0V, V_{GE} = \pm 20V$	-	-	200	nA	
	Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V, I_c = 75mA$	6.2	6.7	7.2	V	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_c = 75A$	Tj=25°C	-	1.90	2.35	V
				Tj=125°C	-	2.20	-	
				Tj=150°C	-	2.30	-	
		$V_{CE(sat)}$ (chip)	$V_{GE} = 15V$ $I_c = 75A$	Tj=25°C	-	1.60	2.05	
				Tj=125°C	-	1.90	-	
				Tj=150°C	-	2.00	-	
	Input capacitance	$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$	-	4.9	-	nF	
	Turn-on time	$t_{on}$	$V_{CC} = 300V$ $I_c = 75A$ $V_{GE} = +15 / -15V$ $R_G = 30\Omega$	-	0.36	1.20	μs	
		$t_r$		-	0.25	0.60		
		$t_r(i)$		-	0.07	-		
	Turn-off time	$t_{off}$	$R_G = 30\Omega$	-	0.52	1.20	μs	
		$t_f$		-	0.03	0.45		
Forward on voltage	$V_F$ (terminal)	$I_F = 75A$	Tj=25°C	-	1.90	2.35	V	
			Tj=125°C	-	1.80	-		
			Tj=150°C	-	1.75	-		
	$V_F$ (chip)	$I_F = 75A$	Tj=25°C	-	1.60	2.05		
			Tj=125°C	-	1.50	-		
			Tj=150°C	-	1.45	-		
Reverse recovery time	$t_{rr}$	$I_F = 75A$	-	-	0.35	μs		
Brake	Zero gate voltage collector current	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 600V$	-	-	1.0	mA	
	Gate-Emitter leakage current	$I_{GES}$	$V_{CE} = 0V$ $V_{GE} = +20 / -20V$	-	-	200	nA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_c = 50A$	Tj=25°C	-	1.80	2.25	V
				Tj=125°C	-	2.10	-	
				Tj=150°C	-	2.20	-	
		$V_{CE(sat)}$ (chip)	$V_{GE} = 15V$ $I_c = 50A$	Tj=25°C	-	1.60	2.05	
				Tj=125°C	-	1.90	-	
				Tj=150°C	-	2.00	-	
	Turn-on time	$t_{on}$	$V_{CE} = 300V$ $I_c = 50A$ $V_{GE} = +15 / -15V$ $R_G = 43\Omega$	-	0.36	1.20	μs	
		$t_r$		-	0.25	0.60		
	Turn-off time	$t_{off}$	$R_G = 43\Omega$	-	0.52	1.20	μs	
		$t_f$		-	0.03	0.45		
	Reverse current	$I_{RRM}$	$V_R = 600V$	-	-	1.00	mA	
	Converter	Forward on voltage	$V_{FM}$ (chip)	terminal	-	1.55	2.00	V
				chip	-	1.25	-	
Reverse current	$I_{RRM}$	$V_R = 800V$	-	-	1.0	mA		
Thermistor	Resistance	R	T = 25°C	-	5000	-	Ω	
			T = 100°C	465	495	520		
B value	B	T = 25 / 50°C	3305	3375	3450	K		

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.50	°C/W
		Inverter FWD	-	-	0.95	
		Brake IGBT	-	-	0.71	
		Converter Diode	-	-	0.82	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-	

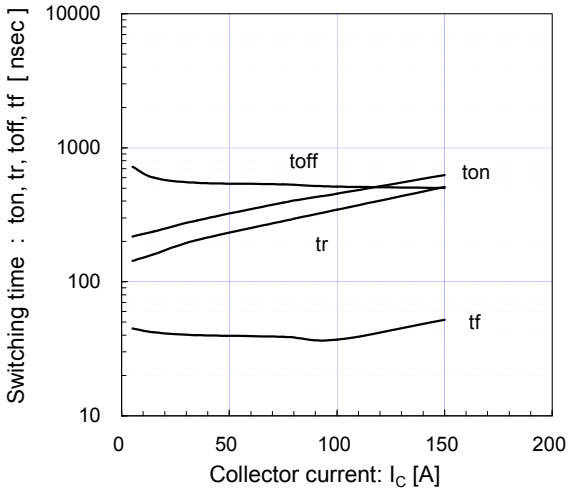
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)



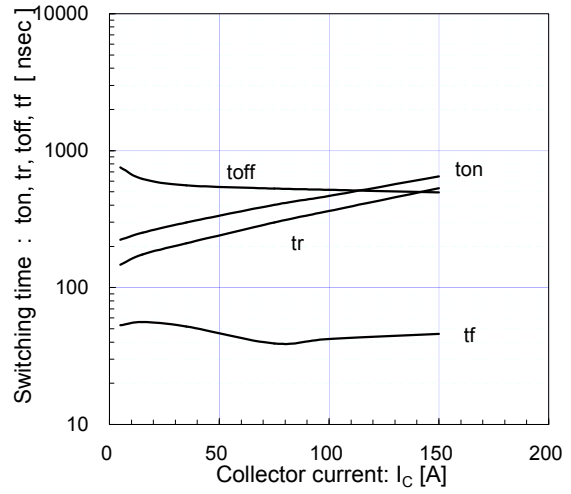
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=30\Omega, T_j=125^\circ C$



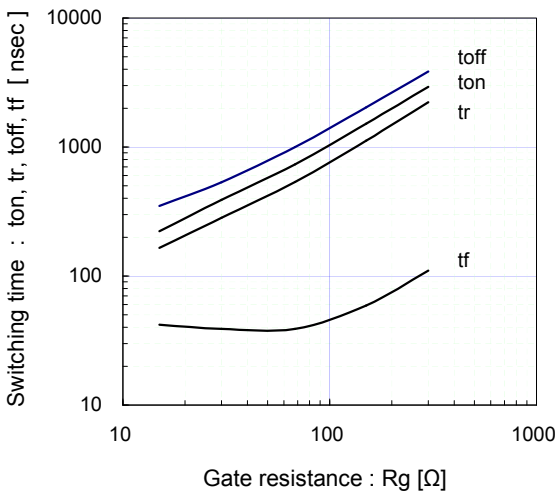
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=30\Omega, T_j=150^\circ C$



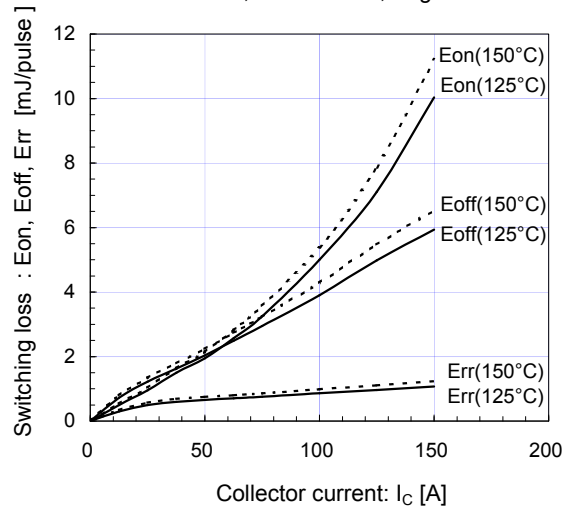
[ Inverter ]

Switching time vs. gate resistance (typ.)  
 $V_{cc}=300V, I_c=75A, V_{GE}=\pm 15V, T_j=125^\circ C$



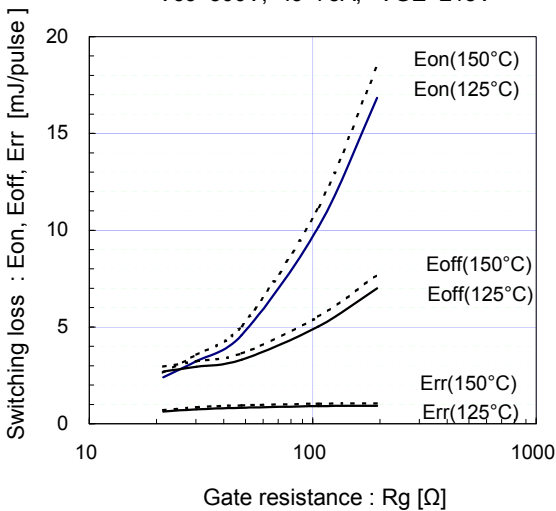
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Switching loss vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=30\Omega$



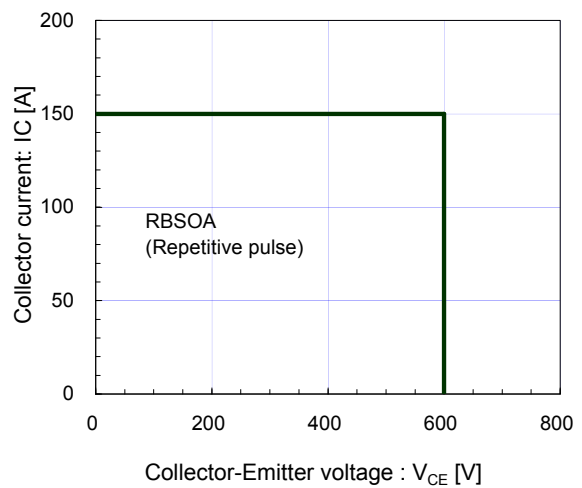
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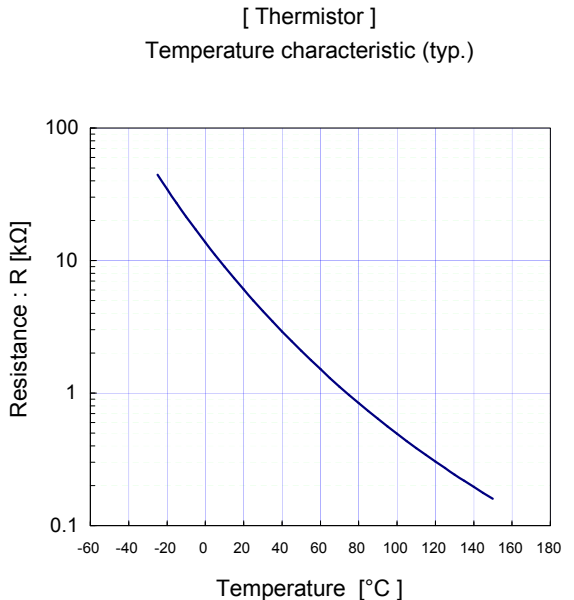
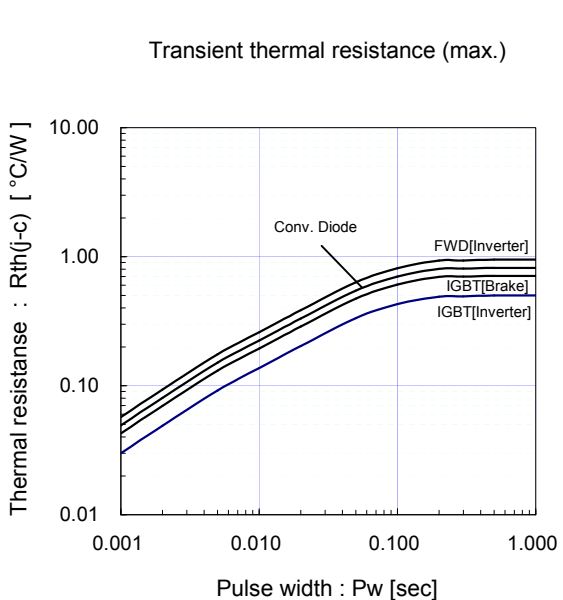
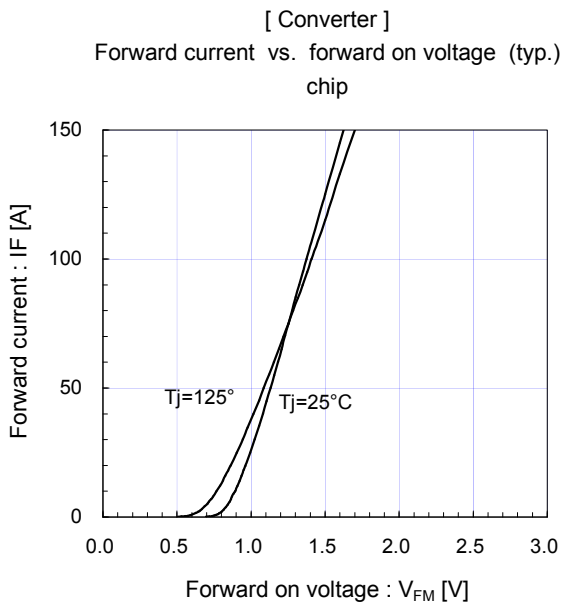
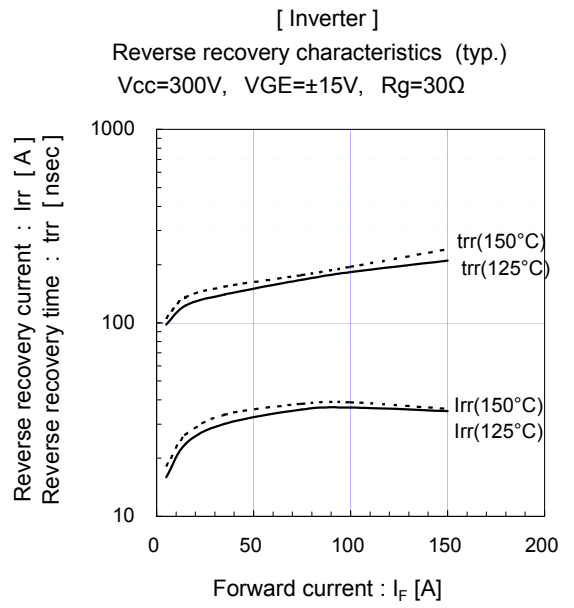
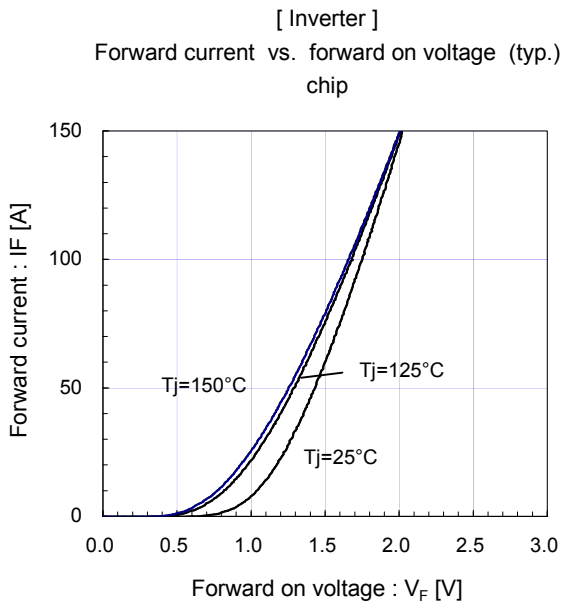
Switching loss vs. gate resistance (typ.)  
 $V_{cc}=300V, I_c=75A, V_{GE}=\pm 15V$



[ Inverter ]

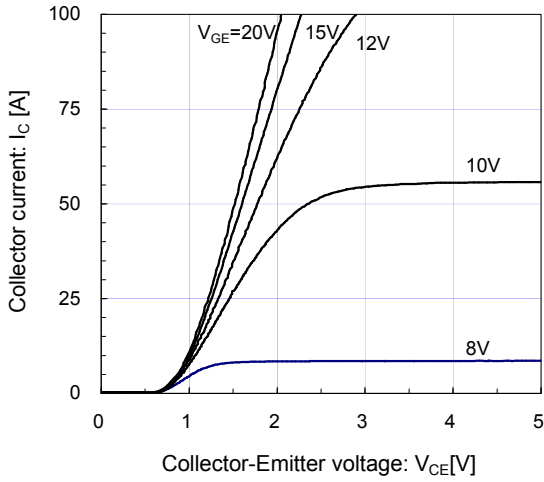
Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE} \leq 15V, R_g \geq 30\Omega, T_j \leq 125^\circ C$





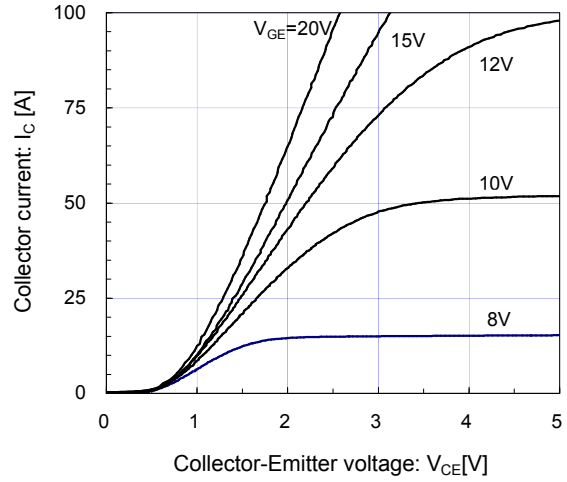
[ Brake ]

Collector current vs. Collector-Emittor voltage (typ.)  
T<sub>j</sub>= 25°C / chip



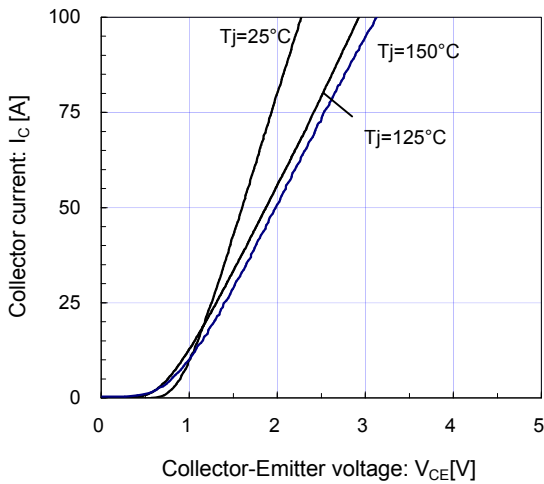
[ Brake ]

Collector current vs. Collector-Emittor voltage (typ.)  
T<sub>j</sub>= 150°C / chip



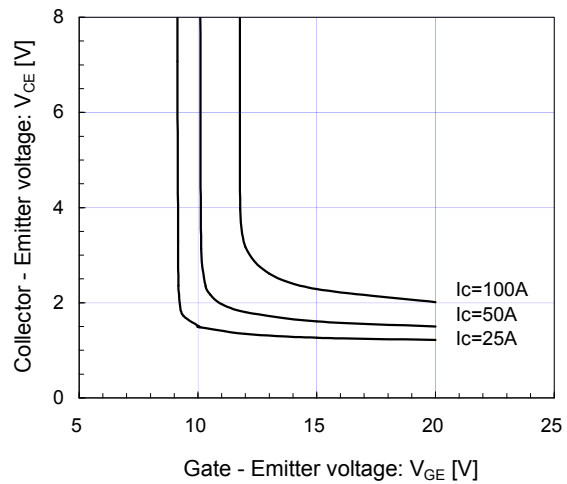
[ Brake ]

Collector current vs. Collector-Emittor voltage (typ.)  
V<sub>GE</sub>=15V / chip



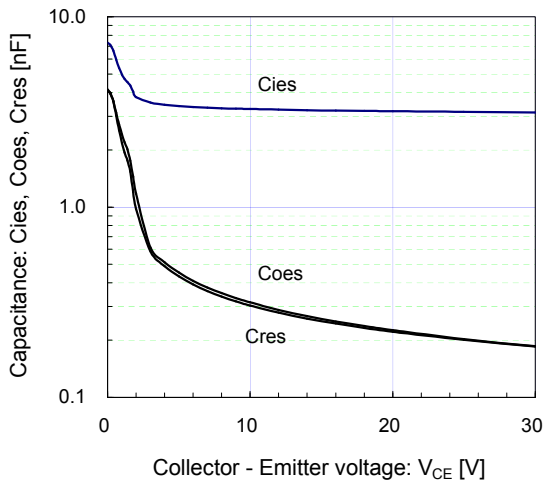
[ Brake ]

Collector-Emittor voltage vs. Gate-Emittor voltage (typ.)  
T<sub>j</sub>= 25°C / chip



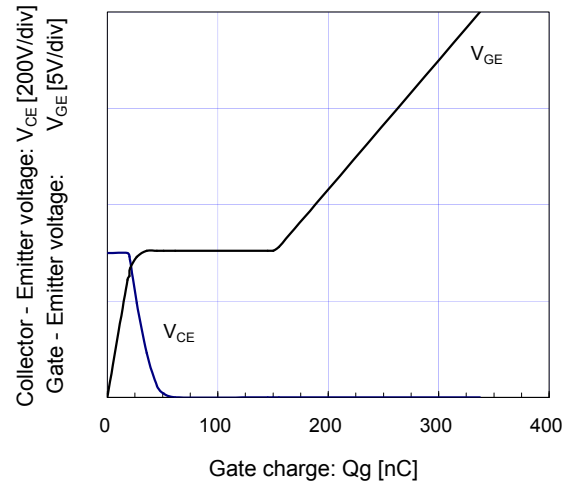
[ Brake ]

Capacitance vs. Collector-Emittor voltage (typ.)  
V<sub>GE</sub>=0V, f= 1MHz, T<sub>j</sub>= 25°C



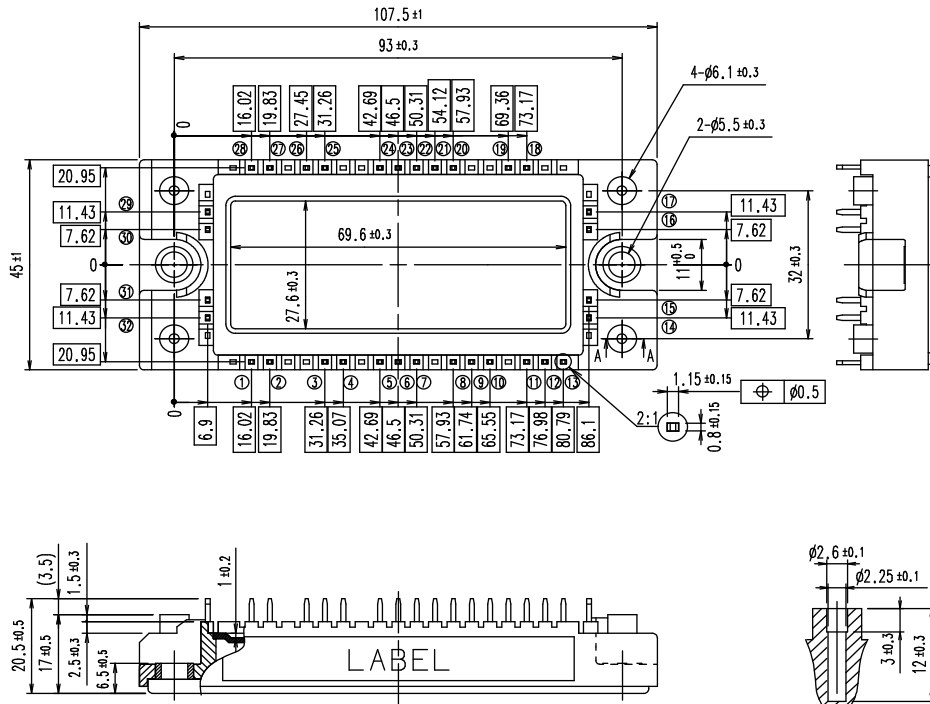
[ Brake ]

Dynamic gate charge (typ.)  
V<sub>CC</sub>=300V, I<sub>c</sub>=75A, T<sub>j</sub>= 25°C



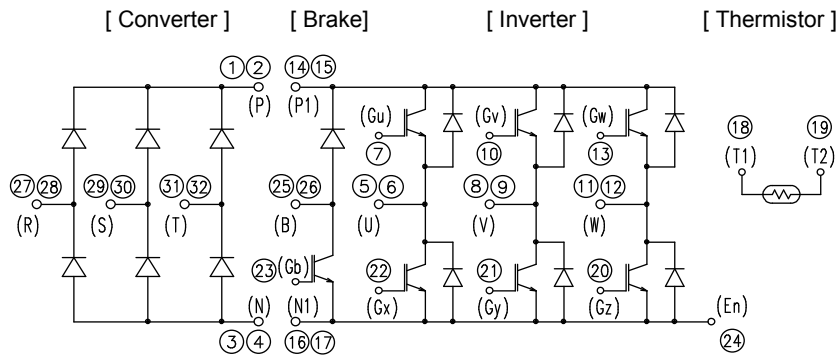
Outline Drawings, mm

□ shows theoretical dimension.  
 ( ) shows reference dimension.



Section A-A

Equivalent Circuit Schematic



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